# Embedded Systems

## Lab 2

http://user.engineering.uiowa.edu/~rbeichel/lectures/es\_s19/lab2/index.html

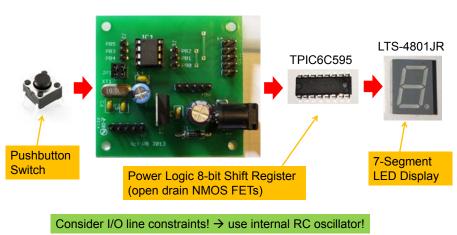
Note: each group will get one power shift register IC and one 7-segment display module from one of the TAs.

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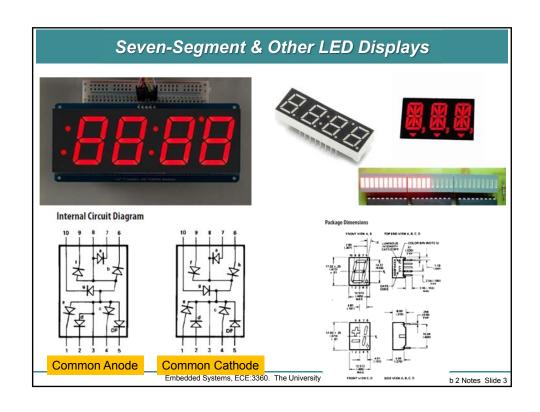
# Lab 2 ("Hexadecimal Up/Down Counter") – Hardware and Software Considerations

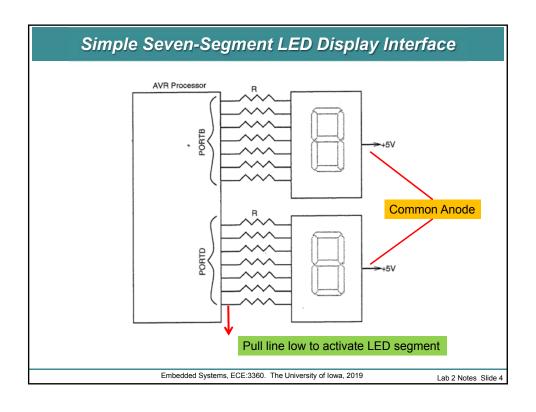
The user can control the counter by using one pushbutton
 ⇒see website for a detailed description of required functionality and datasheets

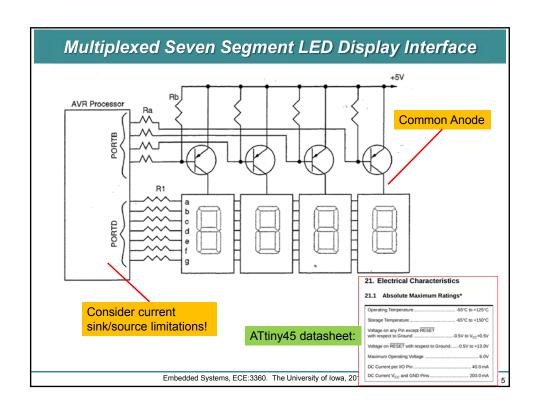


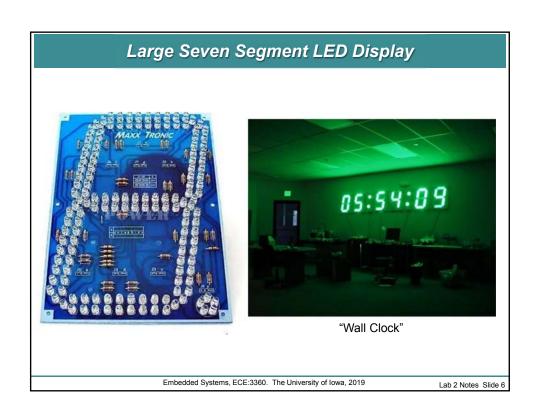
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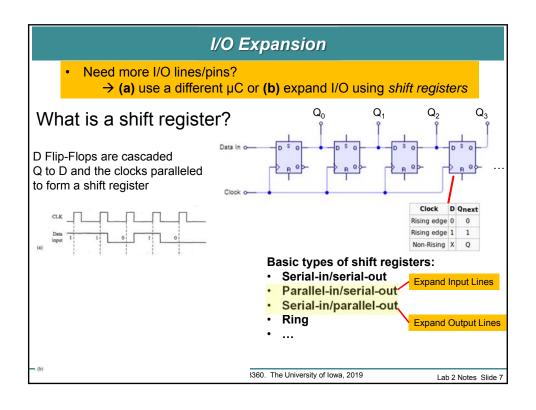
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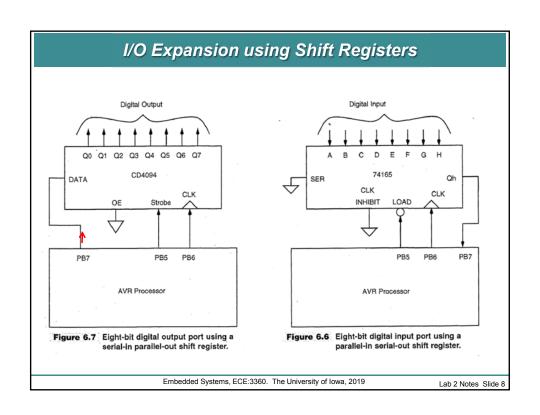


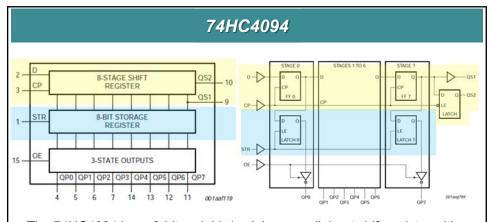








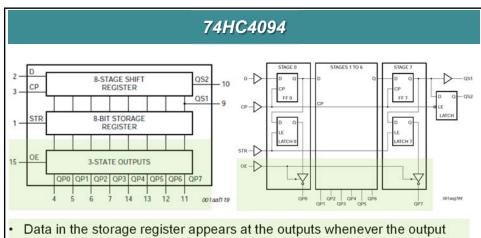




- The 74HC4094 is an 8-bit serial-in/serial- or parallel-out shift register with a storage register and 3-state outputs.
- Both the shift and storage register have separate clocks.
- The device features a serial input (D) and serial outputs to enable cascading.
- · Data is shifted on the LOW-to-HIGH transitions of the CP input.
- The data in the shift register is transferred to the storage register when the STR input is HIGH.

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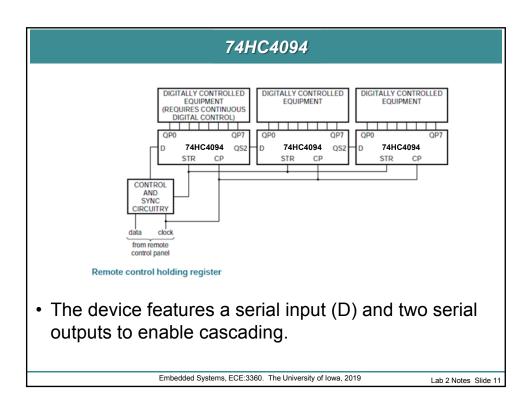
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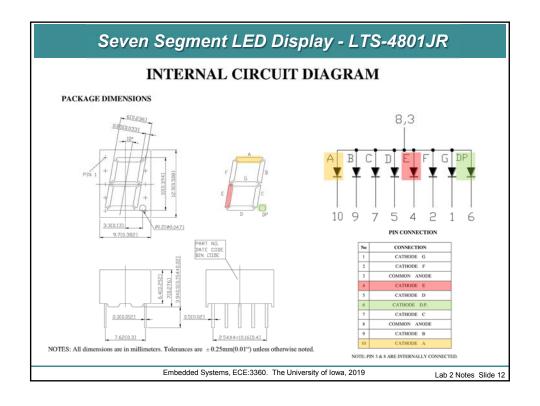


- Data in the storage register appears at the outputs whenever the output enable input (OE) is HIGH.
- A LOW on OE causes the outputs to assume a high-impedance OFF-state.
- Operation of the OE input does not affect the state of the registers.

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### LTS-4801JR

### ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	70	mW
Peak Forward Current Per Segment	90	mA
(1/10 Duty Cycle, 0.1ms Pulse Width)		
Continuous Forward Current Per Segment	25	mA
Derating Linear From 25°C Per Segment	0.33	mA/ºC
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature 1/16 inch Below Seati	ng Plane for 3 Seconds at 260°C	

 $\rightarrow$  see datasheet for relation between I<sub>F</sub> and V<sub>F</sub>

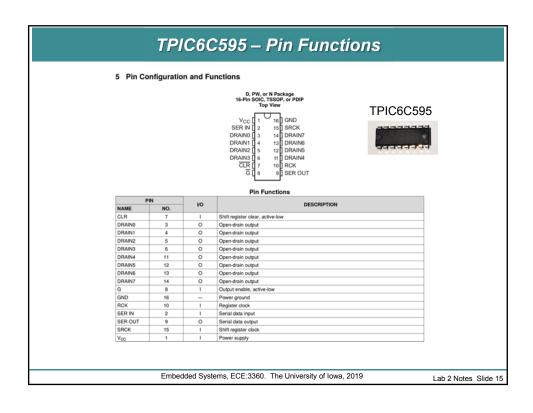
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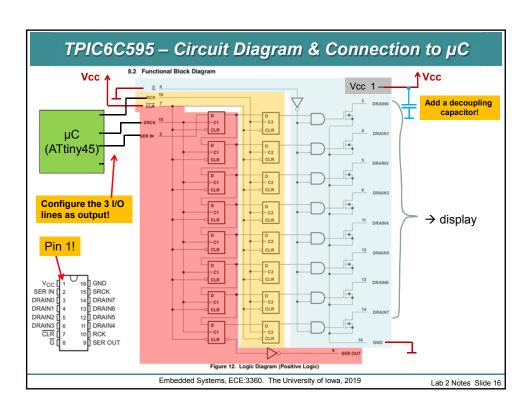
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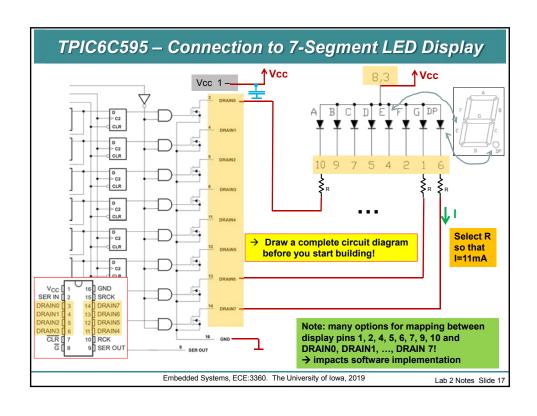
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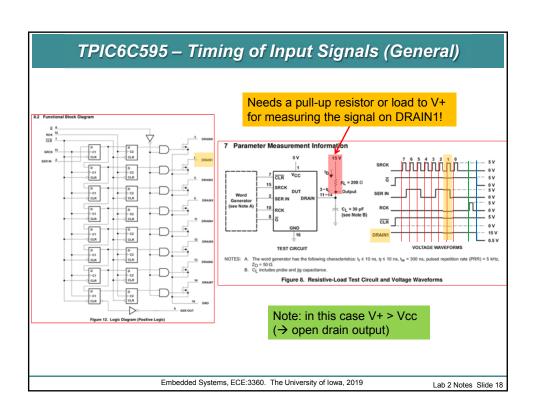
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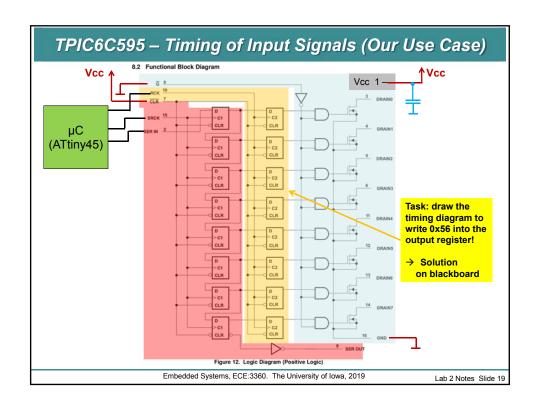
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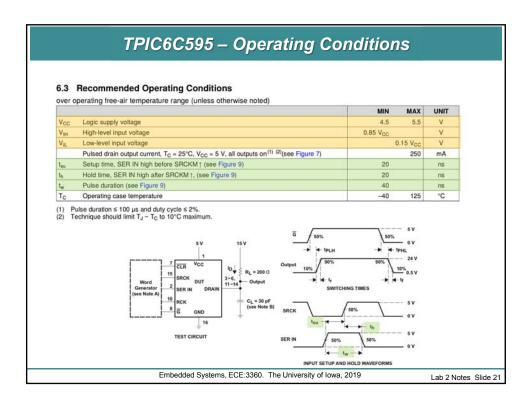


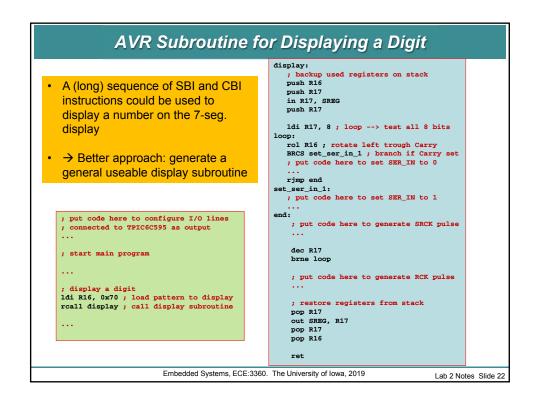


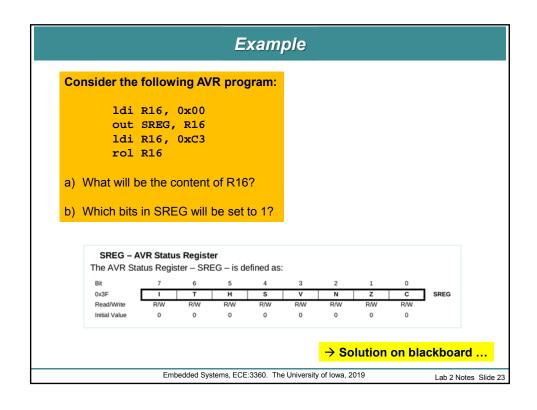


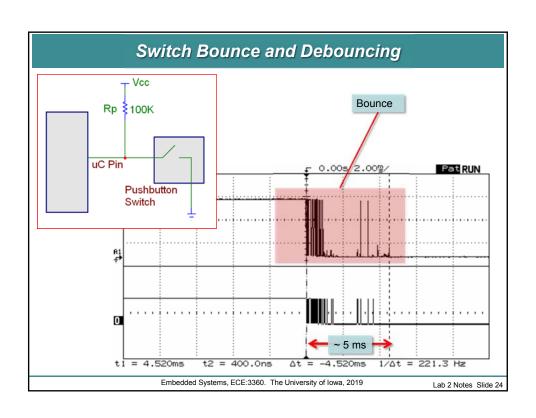


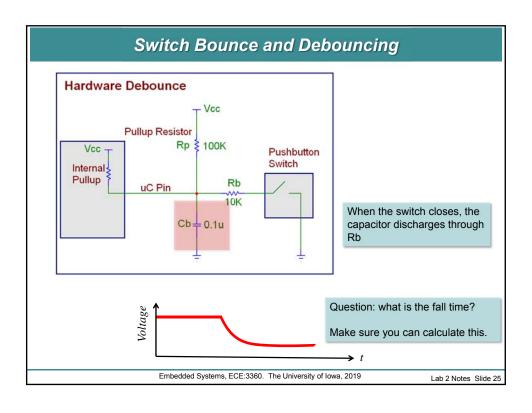
### TPIC6C595 - Absolute Maximum Ratings → Values of voltage, current, temperature, power dissipation etc., which should not be exceeded at any time → otherwise deterioration/destruction of the IC may take place 6.1 Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted) (1) MIN MAX UNIT Logic supply voltage (2) \_0.3 Logic input voltage -0.3 Power DMOS drain-to-source voltage (3) Continuous source-to-drain diode anode current 250 Pulsed source-to-drain diode anode current (4) mΑ Pulsed drain current, each output, all outputs on, $T_C = 25^{\circ}C^{(4)}$ 250 mΑ Continuous drain current, each output, all outputs on, T<sub>C</sub> = 25°C(4 100 mA Peak drain current single output, T<sub>C</sub> = 25°C(4) 250 mA Single-pulse avalanche energy (see Figure 11) 30 mJ Avalanche current<sup>(5)</sup> 0 200 mA Continuous total dissipation See Ther °C Operating virtual junction temperature -40 150 Operating case temperature Storage temperature 150 °C (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. (2) All voltage values are with respect to GND. (3) Each power DMOS source is internally connected to GND. (4) Pulse duration ≤ 100 ys and duty cycle ≤ 2%. (5) DRAIN supply voltage = 15 V, starting junction temperature (T<sub>JS</sub>) = 25°C, L = 1.5 H, I<sub>AS</sub> = 200 mA (see Figure 11). Embedded Systems, ECE:3360. The University of Iowa, 2019 Lab 2 Notes Slide 20











### Software Debounce

**One idea**. Sample n times at regular intervals, say 10 ms apart. Count how many times the switch is zero. If this is larger than the number of times the switch is high, consider the switch pressed.

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